

## BU900TP

## NPN power TRILINTON™

#### Features

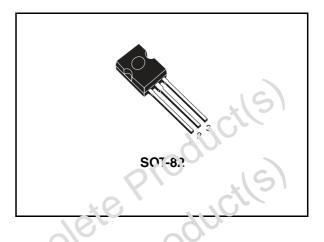
- Integrated high voltage active clamping zener
- Clamping energy capability 100% tested
- Very high current gain

### **Applications**

- Engine ignition control
- Switching regulators
- Motor control
- Light ballast

### Description

The BU900TP is a planar, monolithic, high voltage power TRILINTON<sup>™</sup> with a built-in active Zener clamping circuit. This device has been specifically designed for unclamped, inductive applications such as ignition systems, switching regulators, and wherever high voltage and might robustness is required.



r-ngure 1. Interne' schematic diagram  $\begin{pmatrix} (1) \\ B \\ Q_1 \\ Q_2 \\ Q_3 \\ R_1 \\ DS10145 \\ O E \\ O E$ 

required.	DS10145	R <sub>1</sub>	R <sub>2</sub>	(3	
Table 1.         Device f           Part number         Part number	summary Marking	Package		Packaging	. <u></u>
BUQUOTE	BU900TP	SOT-82		Tube	

#### **Electrical ratings** 1

Table 2.	Absolute maximum rating
	Absolute maximum rating

	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage ( $V_{BE} = 0$ )	370	V
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ )	13	V
۱ <sub>C</sub>	Collector current	5	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	8	Α
I <sub>B</sub>	Base current	1 . [9	A
P <sub>tot</sub>	Total dissipation at $T_c = 25^{\circ}C$	55	W
T <sub>stg</sub>	Storage temperature	- 35 '0 150	°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C
Table 3.	Thermal data	JUCIL	
Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-c ase	2.27	°C/W
*eP	roducils, obsor		

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case	2.27	°C/W

#### **Electrical characteristics** 2

(T<sub>case</sub> = 25°C unless otherwise specified)

Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = 13 V			100	μA
Collector cut-off current $(V_{BE} = 0)$	V <sub>CE</sub> = 370 V			100	μA
Collector-emitter breakdown voltage (V <sub>BE</sub> = 0)	I <sub>C</sub> = 50 mA	370	40	1.60	v
Collector-emitter saturation voltage	$I_{C} = 2.5 A$ $I_{B} = 1 mA$ $I_{C} = 3 A$ $I_{B} = 3 n A$	0)		4	V V
Base-emitter saturation voltage	$I_{\rm C} = 3  {\rm A}$ $I_{\rm b} = 3  {\rm nA}$		NUK	3.5	v
DC current gain	$I_{\rm C} = 1 \text{ A}$ $V_{\rm CE} = 5 \text{ V}$	7000	5		
Secondary breakdown energy	I <sub>C</sub> = 4 <sup>A</sup> . L = 10 mH	80			mJ
oducils	0050				
	ParameterEmitter cut-off current $(I_C = 0)$ Collector cut-off current $(V_{BE} = 0)$ Collector-emitter breakdown voltage $(V_{BE} = 0)$ Collector-emitter saturation voltageBase-emitter saturation voltageDC current gainSecondary breakdown energy	ParameterTest ConditionsEmitter cut-off current $(I_C = 0)$ $V_{EB} = 13 \text{ V}$ Collector cut-off current $(V_{BE} = 0)$ $V_{CE} = 370 \text{ V}$ Collector-emitter breakdown voltage $(V_{BE} = 0)$ $I_C = 50 \text{ mA}$ Collector-emitter breakdown voltage $I_C = 50 \text{ mA}$ Collector-emitter breakdown voltage $I_C = 2.5 \text{ A}$ $I_B = 1 \text{ mA}$ Collector-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ n} \text{ A}$ Base-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ nA}$ DC current gain $I_C = 1 \text{ A}$ $V_{CE} = 5 \text{ V}$ Secondary breakdown $I_C = 4 \text{ A}$ $L = 10 \text{ mH}$	ParameterTest ConditionsMin.Emitter cut-off current $(I_C = 0)$ $V_{EB} = 13 \text{ V}$ $V_{EB} = 13 \text{ V}$ Collector cut-off current $(V_{BE} = 0)$ $V_{CE} = 370 \text{ V}$ $V_{CE} = 370 \text{ V}$ Collector-emitter breakdown voltage $(V_{BE} = 0)$ $I_C = 50 \text{ mA}$ $370$ Collector-emitter breakdown voltage $I_C = 2.5 \text{ A}$ $I_B = 1 \text{ mA}$ $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ Base-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ $I_C = 5 \text{ V}$ DC current gain $I_C = 1 \text{ A}$ $V_{CE} = 5 \text{ V}$ 7000Secondary breakdown energy $I_C = 4 \text{ A}$ $L = 10 \text{ mH}$ 80	ParameterTest ConditionsMin.Typ.Emitter cut-off current $(I_C = 0)$ $V_{EB} = 13 \text{ V}$ Collector cut-off current $(V_{BE} = 0)$ $V_{CE} = 370 \text{ V}$ Collector-emitter breakdown voltage $(V_{BE} = 0)$ $I_C = 50 \text{ mA}$ $370$ Collector-emitter breakdown voltage $I_C = 50 \text{ mA}$ $370$ Collector-emitter saturation voltage $I_C = 2.5 \text{ A}$ $I_B = 1 \text{ mA}$ $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ Base-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ DC current gain $I_C = 1 \text{ A}$ $V_{CE} = 5 \text{ V}$ 7000Secondary breakdown energy $I_C = 4 \text{ A}$ $L = 10 \text{ mH}$ 80	ParameterTest ConditionsMin.Typ.Max.Emitter cut-off current $(I_C = 0)$ $V_{EB} = 13 \text{ V}$ 100Collector cut-off current $(V_{BE} = 0)$ $V_{CE} = 370 \text{ V}$ 100Collector-emitter breakdown voltage $(V_{BE} = 0)$ $I_C = 50 \text{ mA}$ 370100Collector-emitter breakdown voltage $(V_{BE} = 0)$ $I_C = 50 \text{ mA}$ 370100Collector-emitter saturation voltage $I_C = 2.5 \text{ A}$ $I_B = 1 \text{ mA}$ 4Base-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ 4Base-emitter saturation voltage $I_C = 3 \text{ A}$ $I_B = 3 \text{ n A}$ 3.5DC current gain $I_C = 1 \text{ A}$ $V_{CE} = 5 \text{ V}$ 70005Secondary breakdown energy $I_C = 4 \text{ A}$ $L = 10 \text{ mH}$ 801

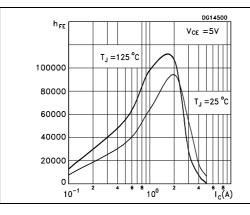
Table 4. **Electrical characteristics** 

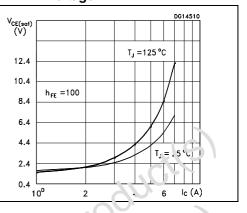
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### 2.1 Electrical characteristics (curves)

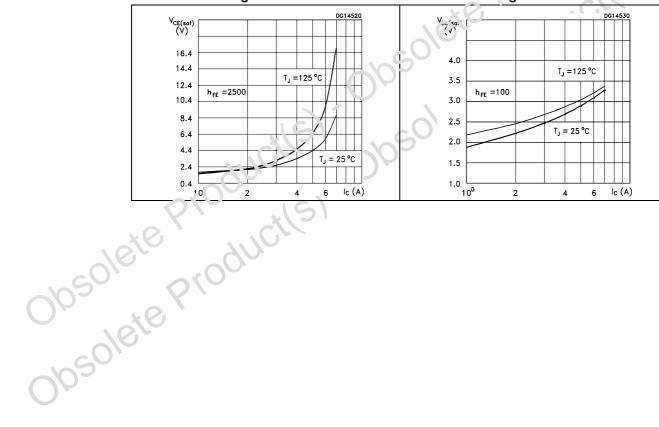
#### Figure 2. DC current gain

## Figure 3. Collector-emitter saturation voltage





# Figure 4. Collector-emitter saturation Figure 5. Bss-an.iter saturation voltage voltage





### 3 Package mechanical data

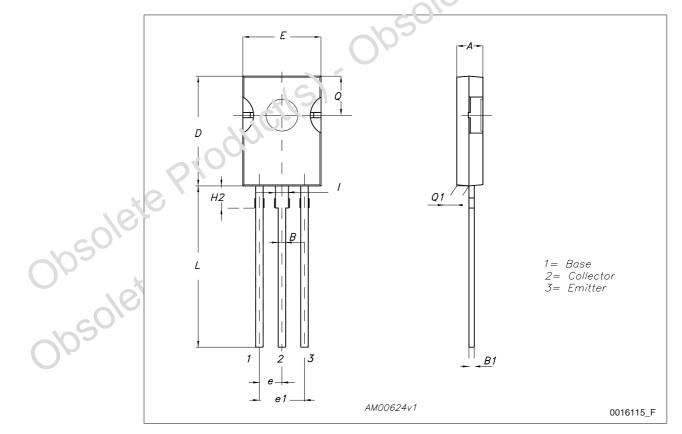
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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SOT-82 mechanical data	
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Dim.		mm	
Dill.	Min.	Тур.	Max.
A	2.40		2.70
В	0.70		0.90
B1	0.49		0.75
D	10.50		10.80
E	7.40		7.80
е	2.04		2.54
e1	4.07		5.03
L	15.40		16
Q		3.80	20.
Q1	1	01	1.30
H2		2.07	
I		1.27	





### 4 Revision history

#### Table 5. Document revision history

Date	Revision	Changes
02-Aug-2007	1	First release.
19-Nov-2008	2	Document status changed from preliminary to datasheet.

Obsolete Product(s) - Obsolete Product(s) Obsolete Product(s) - Obsolete Product(s)

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